

Experimental results and applications of FBK-irst SiPM pixels and matrices by the DASIPM collaboration

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On behalf of the DASIPM collaboration

Universities/INFN sections of Pisa, Bari, Bologna, Perugia, Trento and FBK-irst

<http://sipm.itc.it/>

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Outline

- SiPMs by FBK-irst (previously ITC-irst)
- Results:
 - Characterization
 - Evaluation for PET applications
- Application to medical imaging: small animal PET and PET/MR.

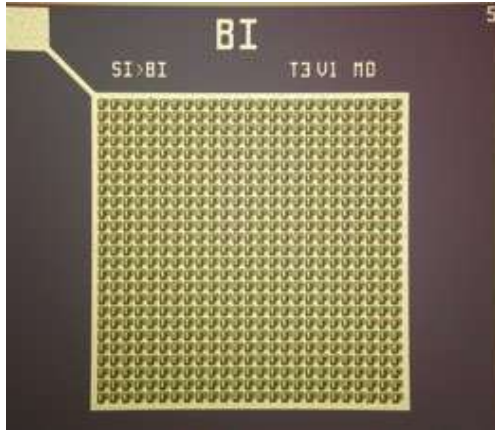
DASIPM collaboration

- SiPMs development at FBK-irst (Center for Scientific and Technological Research, Trento, Italy) within the DASIPM collaboration.
- **DASIPM: Development and Application of Silicon Photomultipliers.**
Universities/INFN sections of Bari, Bologna, Perugia, Pisa, Trento + FBK-irst.
 - SiPM development
 - Electronics development (Dedicated ASIC + readout system)
 - Application to:
 - Space physics (AMS TOF)
 - Fiber tracking
 - **Medical imaging: Small animal PET.**

SiPM development at FBK-irst

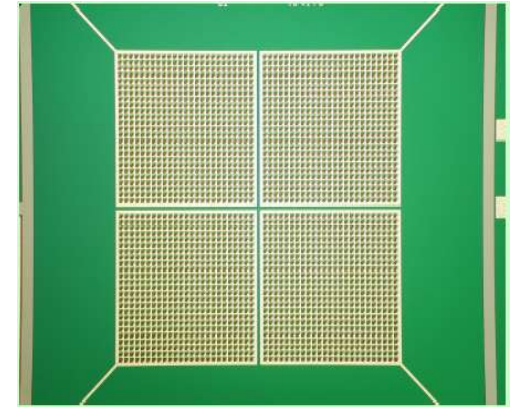
- Development process since beginning of 2005.
- Aimed at:
 - Fabrication and optimization of blue sensitive devices.
 - Fabrication of SiPM matrices in common substrate.
- Perfect understanding of the devices and expected results.
- Development process in several steps:
 - Simulation
 - Test functionality
 - Test reproducibility
 - Reduction of optical cross-talk
 - Reduction of dark noise with gettering techniques.
 - Optimization of the fill factor —▶ New SiPMs to be tested.

SiPMs produced

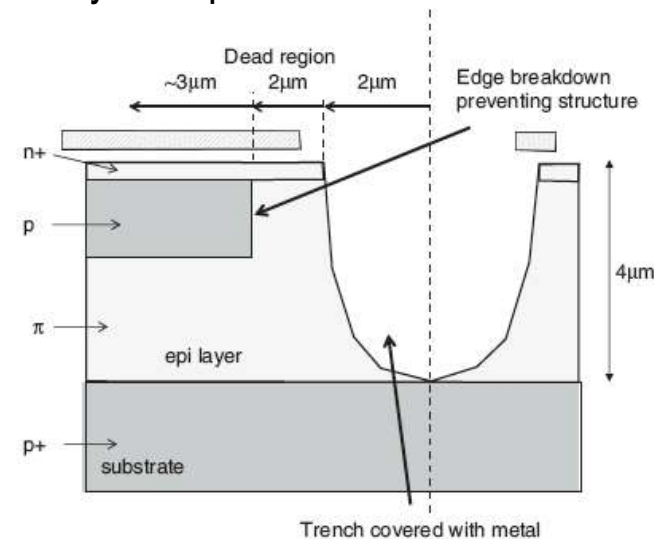


Single SiPMs: 1 mm x 1 mm
area in 1.5 mm x 1.5 mm pitch.

Test matrices 2x2 elements
in common substrate .
same characteristics



- **Structure: $n^+ - p - \pi - p^+$ optimized for blue light:** Shallow n^+ layer + specific antireflective coating.
- 625 (25 x 25) microcells.
- Size: $40 \mu\text{m} \times 40 \mu\text{m}$.
- Polysilicon quenching resistance.
- Fill factor (GF) up to 30%.
- optical trenches to avoid cross-talk.

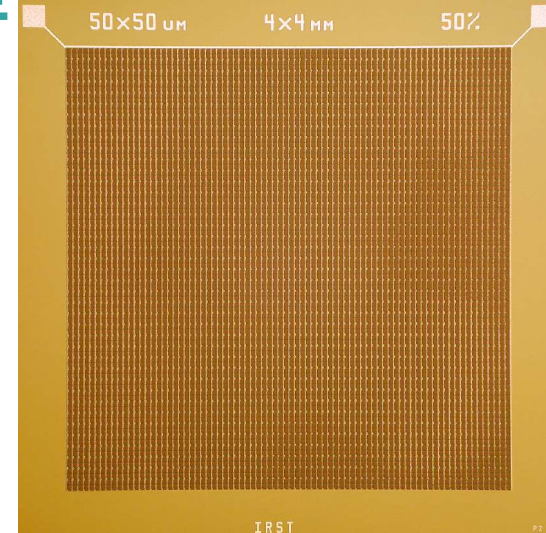
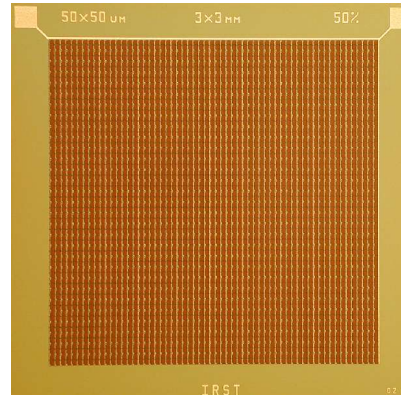
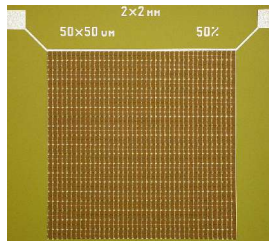
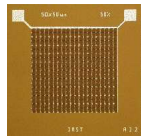
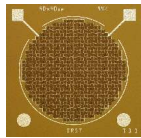


SiPMs from development runs tested

New detectors recently produced

- Different geometry, size, microcell size and GF.

$40 \times 40 \mu\text{m} \Rightarrow \text{GF } 44\%$
 $50 \times 50 \mu\text{m} \Rightarrow \text{GF } 50\%$
 $100 \times 100 \mu\text{m} \Rightarrow \text{GF } 76\%$



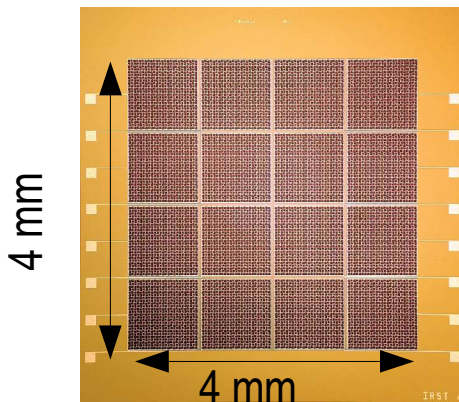
circular (1mm diam) 1x1mm

2x2 mm

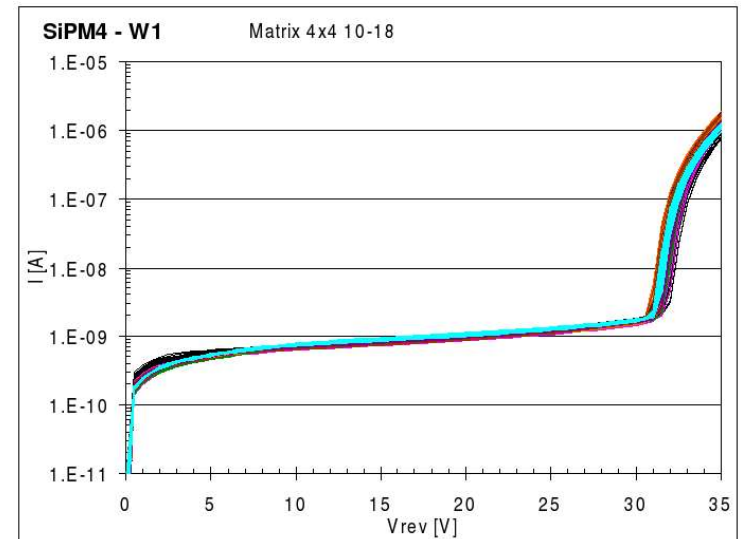
3x3 mm (3600 cells)

4x4 mm (6400 cells)

- Matrices 16 elements (4x4)



IV CURVES OF 9 MATRICES.
VERY UNIFORM
BREAKDOWN POINT



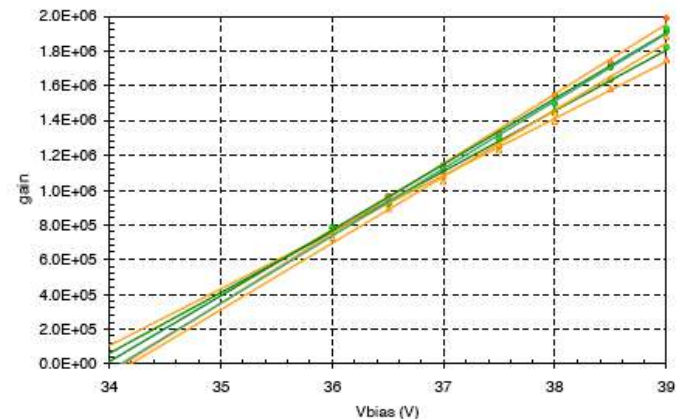
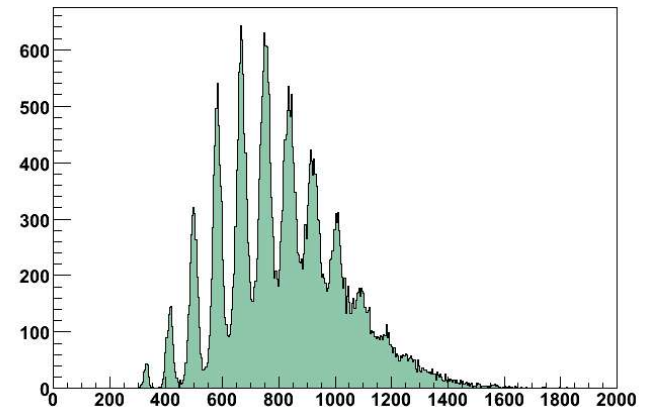
Evaluation of FBK- irst SiPMs for PET and PET/MR

- Characterization
 - Electro-optical characterization
 - Intrinsic timing
 - Photon detection efficiency
 - Variation with temperature
- Evaluation for PET and PET/MR.
 - Energy resolution
 - Coincidence timing resolution.
 - Results in an MR system
 - First results with SiPM matrices

Results: characterization

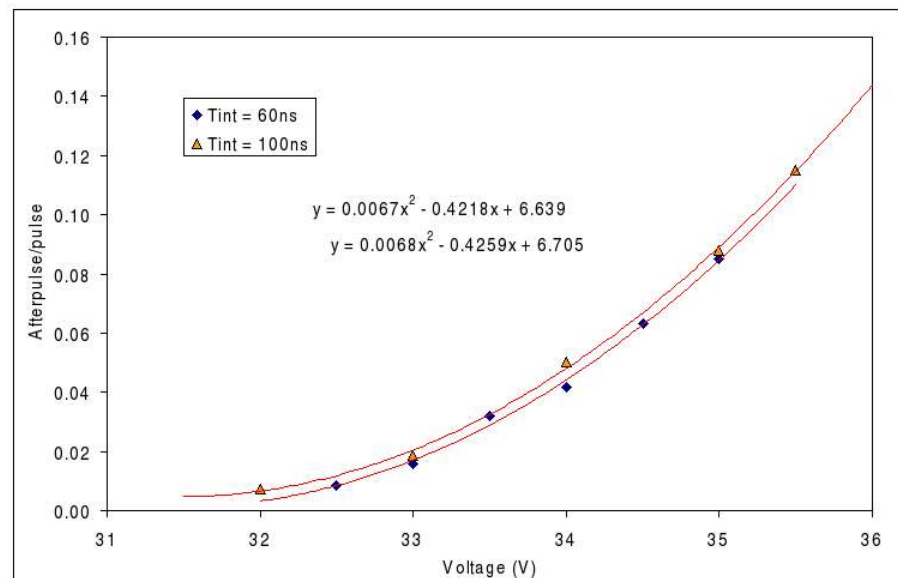
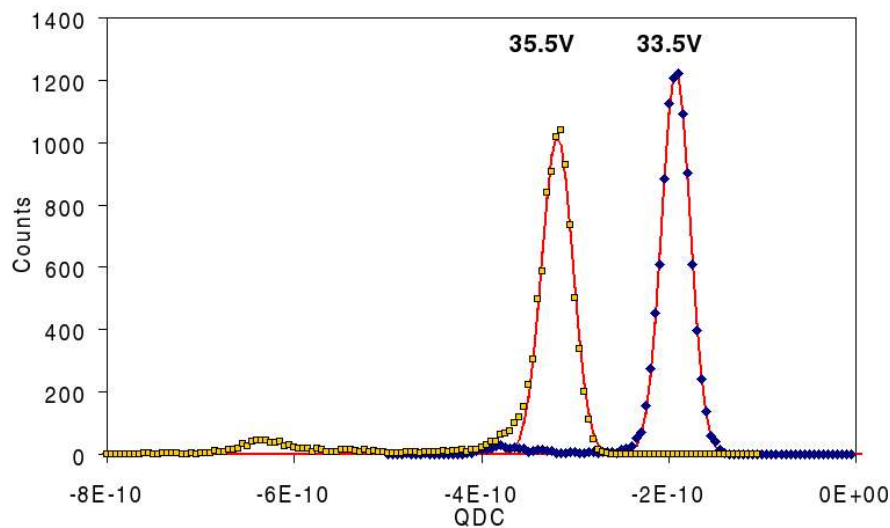
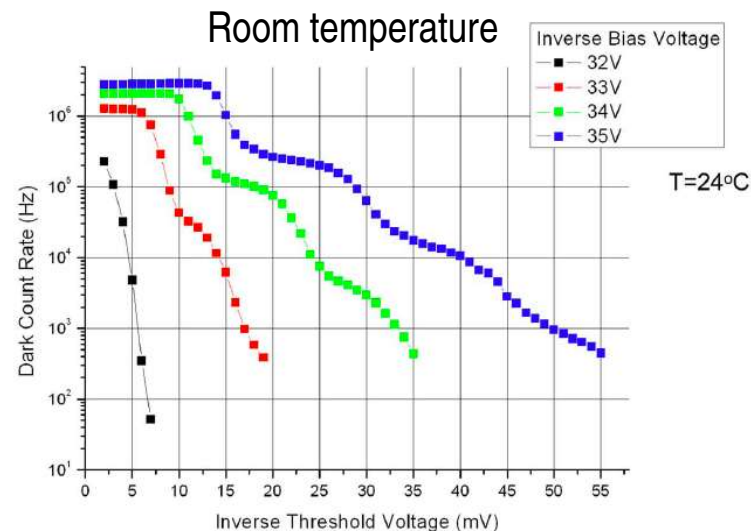
- Breakdown voltage $V_B \sim 30V$, very good uniformity (0.4 V sigma).
- Operation 2-5 V overvoltage.
- Single photoelectron spectrum: well resolved peaks from at room temperature.
- Gain: $\sim 10^6$
 - Linear for a few volts over V_{BD} .
 - Related to the recharge of the diode capacitance C_D from V_{BD} to V_{BIAS} during the avalanche quenching. $G=(V_{BIAS}-V_B) \times C_D/q$

Room temperature



Results: Noise

- Dark rate:
 - 1-3 MHz at 1-2 photoelectron (p.e.) level, ~KHz at 3-4 p.e (room temperature).
 - Not a concern for PET applications.
 - Reduced in the new detectors
- Cross talk below 5% at 4V overvoltage.
- Afterpulse



Photon detection efficiency

$$PDE = QE \times Pt \times GF$$

Quantum efficiency

- Intrinsic quantum efficiency
- Transmission factor of the coating $T=(1-R)$

$$QE = (1 - e^{-\eta x})(1 - R)$$

Probability of photoabsorption once the photons have traversed the coating.

$\eta = \eta(\lambda)$ linear absorption coefficient.

Avalanche triggering probability

$$Pt = Pe + Ph - PePh$$

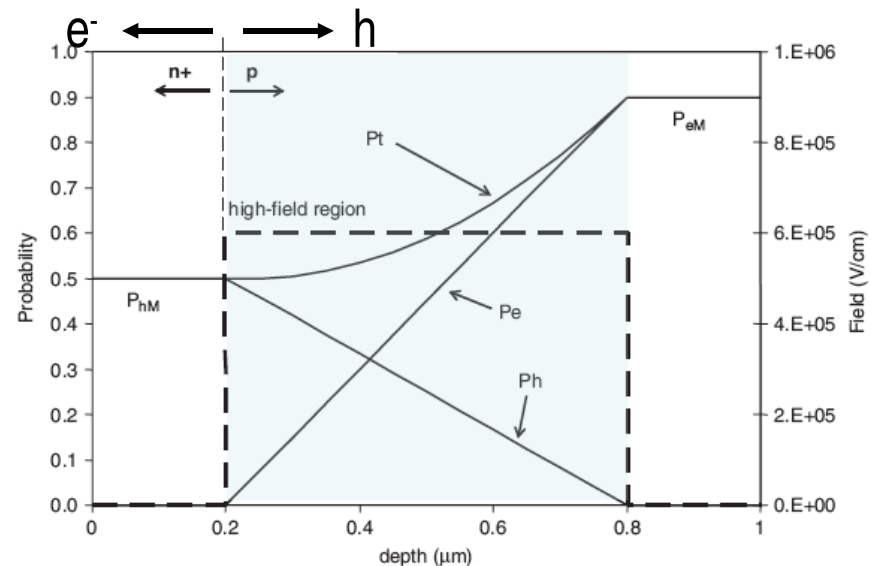
- Electrons have higher probability because of the higher ionization rate ($Pe > Ph$).
- In any case, the higher the V_{bias} , the higher Pt .
- For a given SiPM structure, it depends on the interaction position, i.e., on the wavelength.

Geometrical efficiency:

Active area / Total area of microcell

QE optimization

- n+p structure: Pt higher for photons interacting deeper => very shallow epi layer.
- Anti-reflective coating optimized for 420 nm

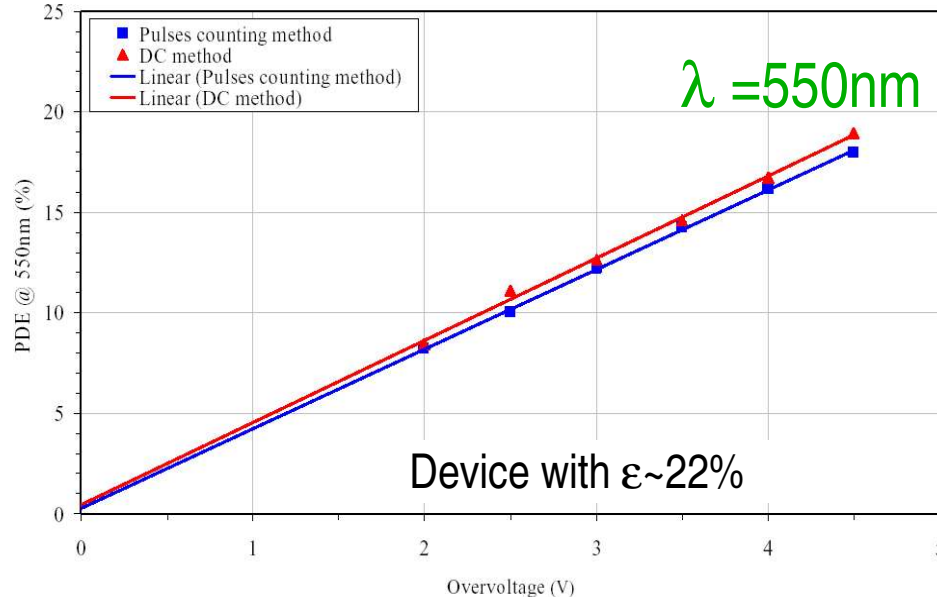
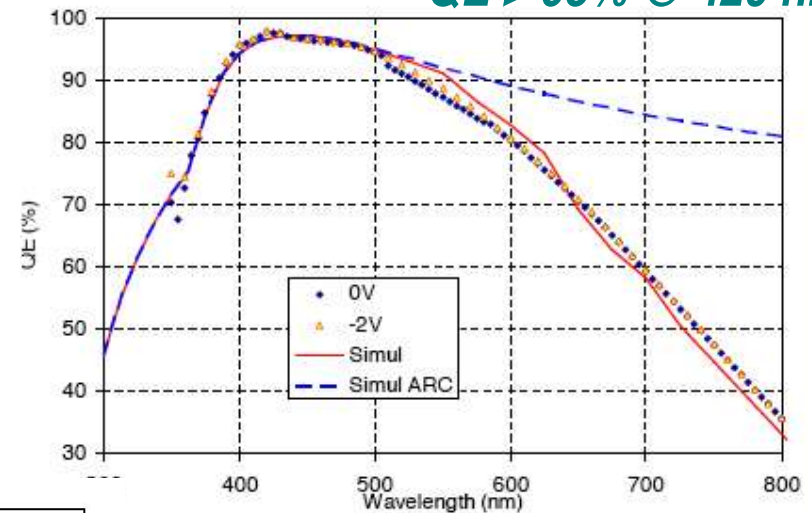


Results: PDE

$$PDE = QE \times Pt \times GF$$

- QE above 95% for 420 nm light wavelength (LSO emission).
- 10% PDE measured at the same wavelength for a device with 20% GF.

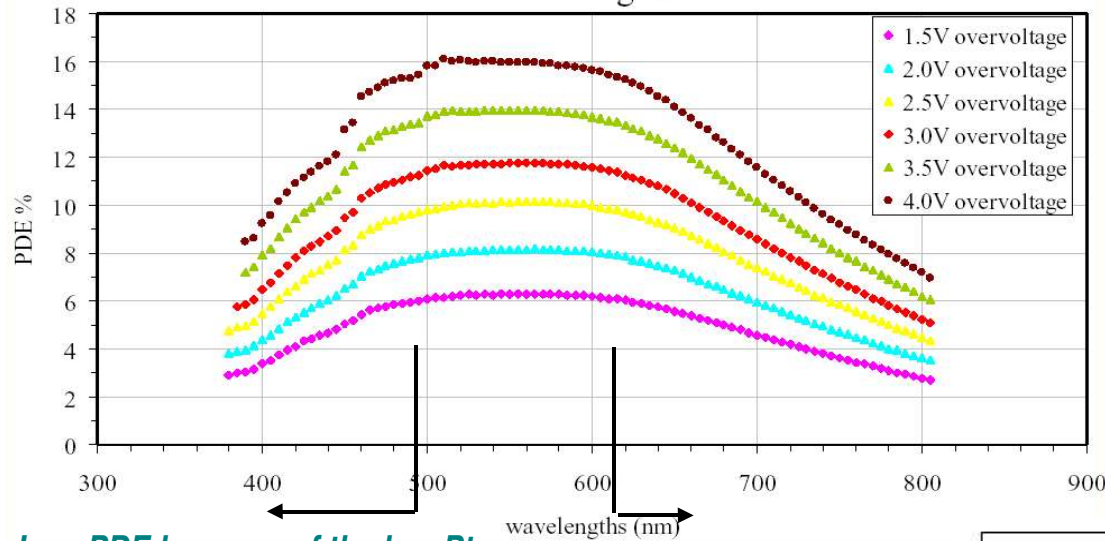
QE > 95% @ 420 nm



Results: PDE II

$$PDE = QE \times Pt \times GF$$

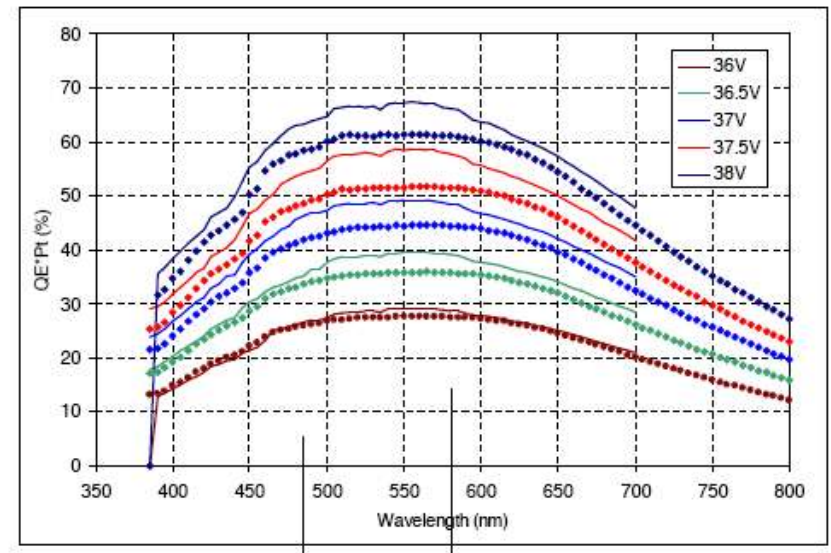
device with $\epsilon_{\text{geom}} \sim 22\%$



*Low PDE because of the low Pt
(holes trigger the avalanche)*

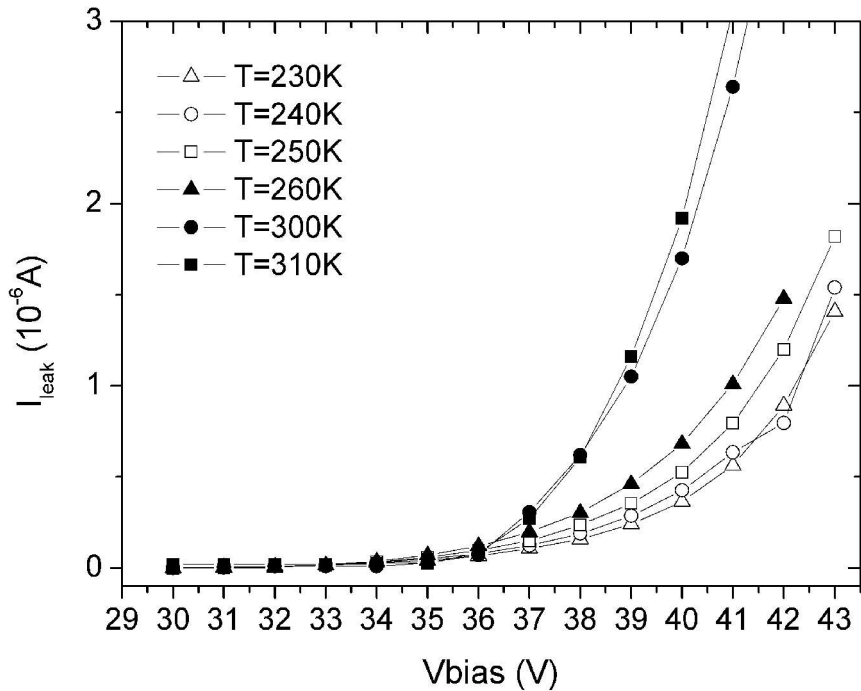
*Low PDE because of
the low QE*

- PDE/GF = QE x Pt is 40% for 420 nm
- Higher PDE expected for optimized GF



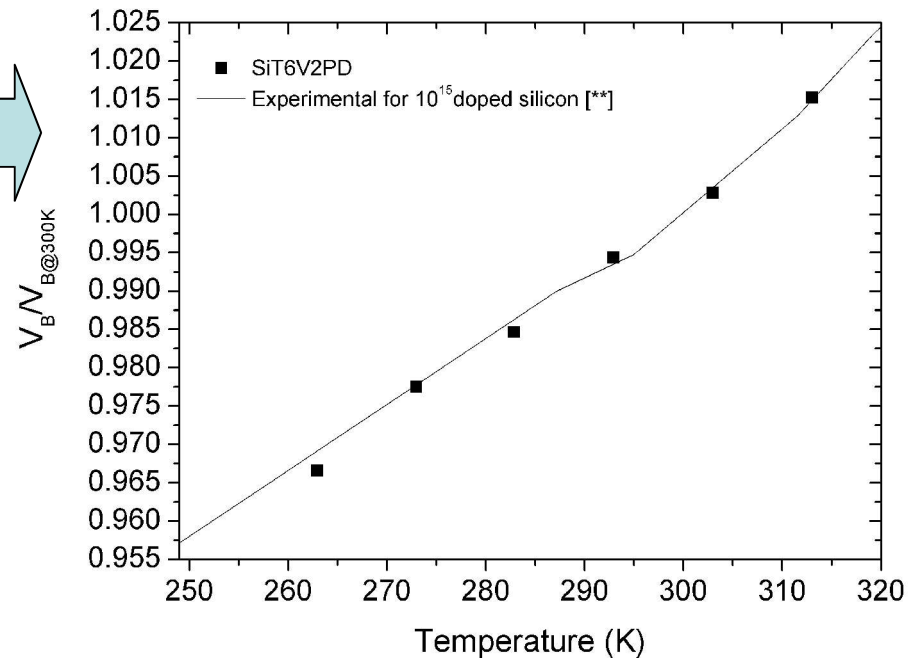
Temperature dependence

- IV curves at different temperature



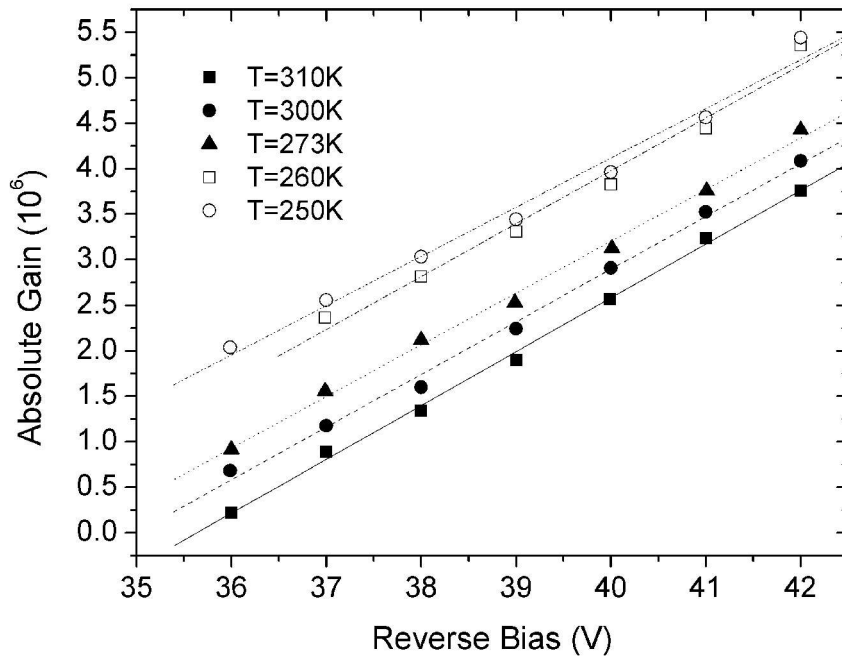
M. Petasecca et al., Perugia(2007)

- Variation of V_{break} with temperature due to variation of Pt



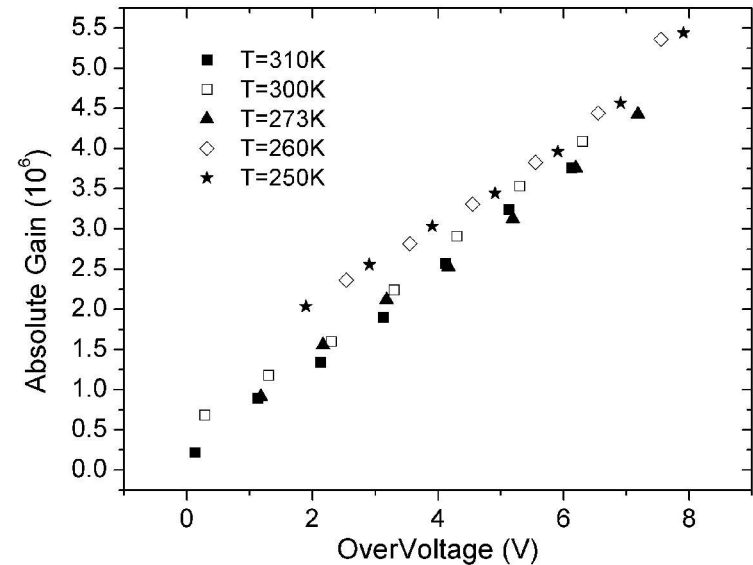
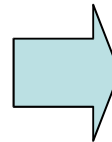
Temperature dependence II

- Gain vs Bias vs Temperature



The residual Gain dependence is due to the variation of V_{break} .

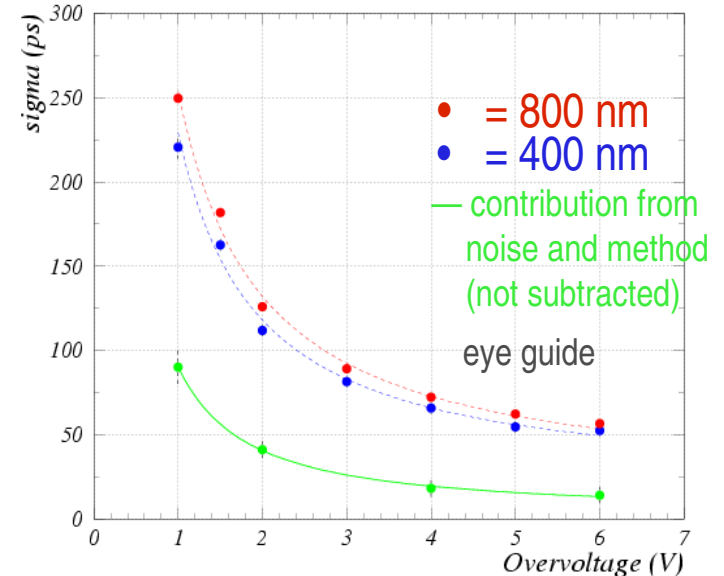
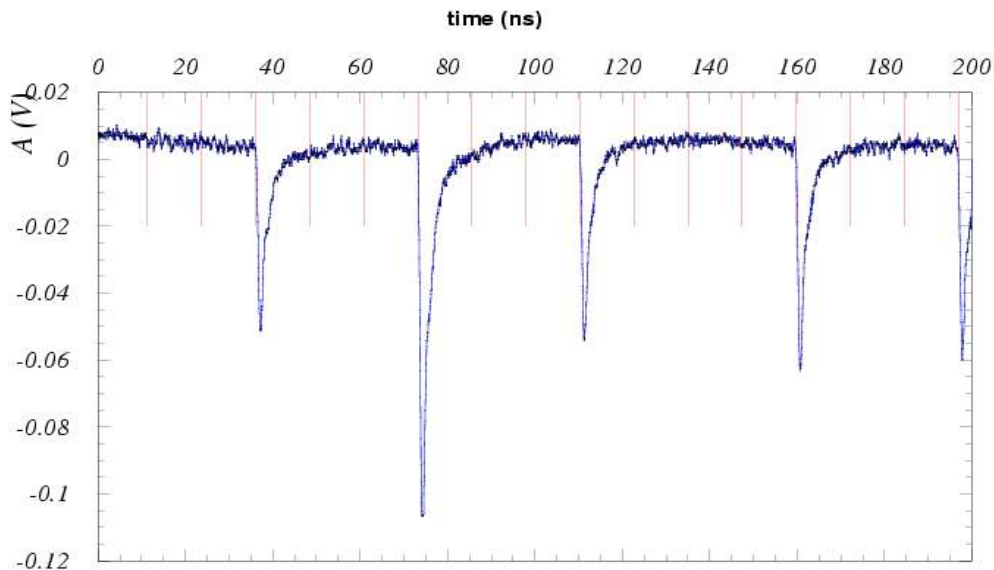
correcting for the variation of V_{break} ...



M. Petasecca et al., Perugia(2007)

Results: intrinsic timing

- Intrinsic timing measured at the s.p.e level: 60 ps sigma for blue light.
- SiPM illuminated with a pulsed laser with 60 fs pulse width and 12.34 ns period, with less than 100 fs jitter.
- Two wavelengths measured: $\lambda = 400 \pm 7$ nm and $\lambda = 800 \pm 15$ nm.
- Time difference between contiguous pulses is determined.

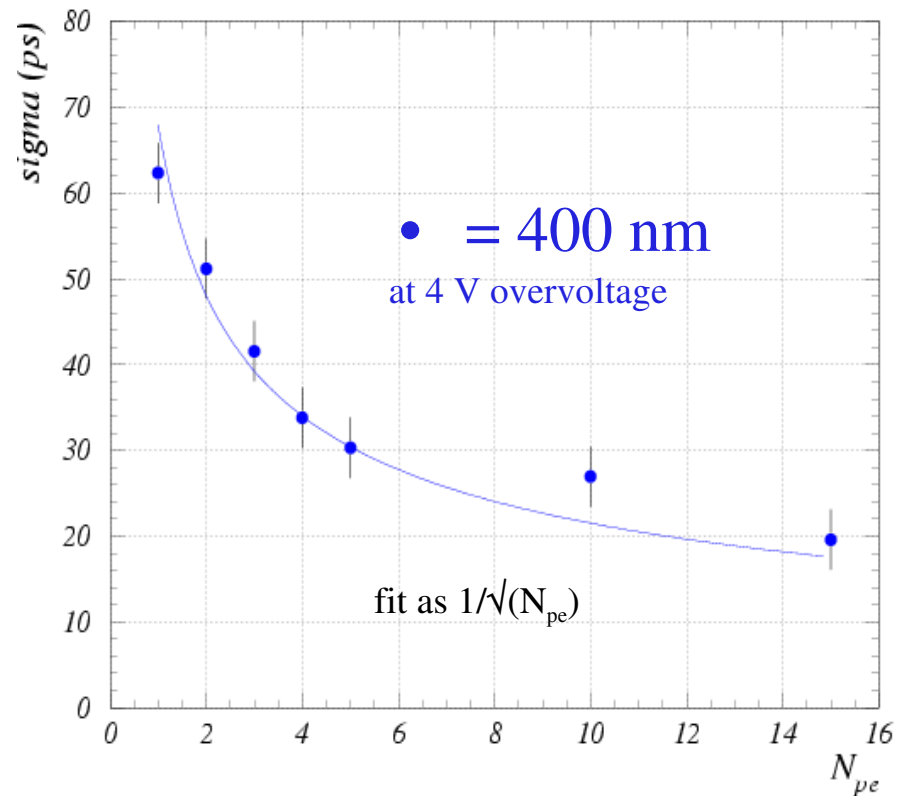


G. Collazuol at VCI 2007, to be published in NIM A.

Results: intrinsic timing II

- The timing decreases with the number of photoelectrons as $1/\sqrt{N_{pe}}$.

20 ps at 15 photoelectrons.



G. Collazuol at VCI 2007, to be published in NIM A.

Results: energy resolution

Energy resolution: **20% FWHM.**

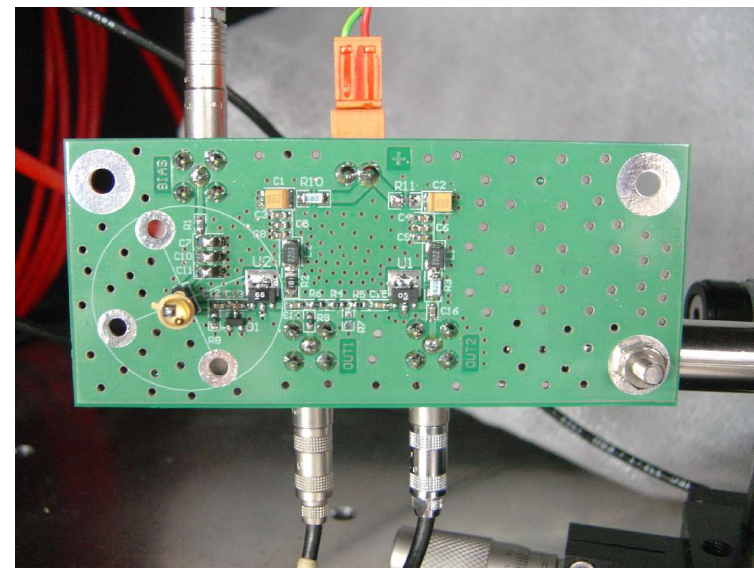
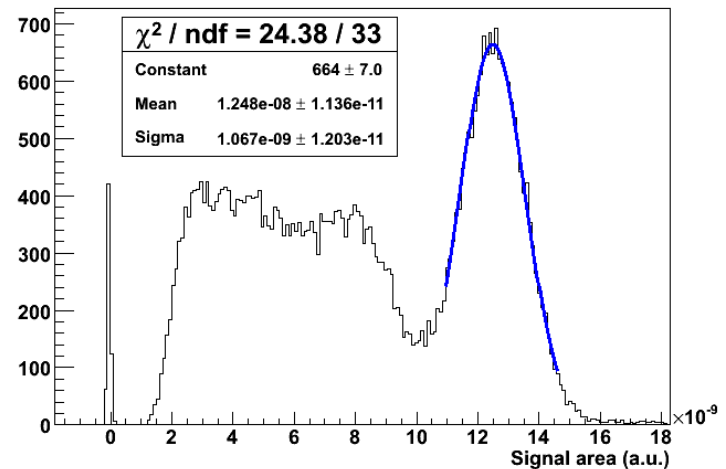
(best result: 17.5 %)

Improvement expected with new SiPMs with higher PDE, better coupling and noise reduction.

Setup:

- 2 LSO 1mm x 1mm x 10mm crystals coupled to 2 SiPMs.
- Home made amplifier board.
- Time coincidence of signals.
- VME QDC for DAQ.
- ^{22}Na source.

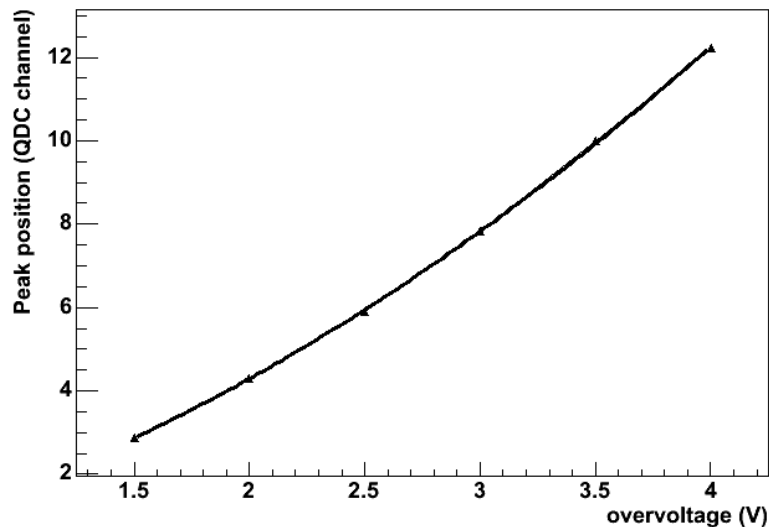
Na-22 energy spectrum (coincidence)



Results: Peak position and energy resolution vs bias

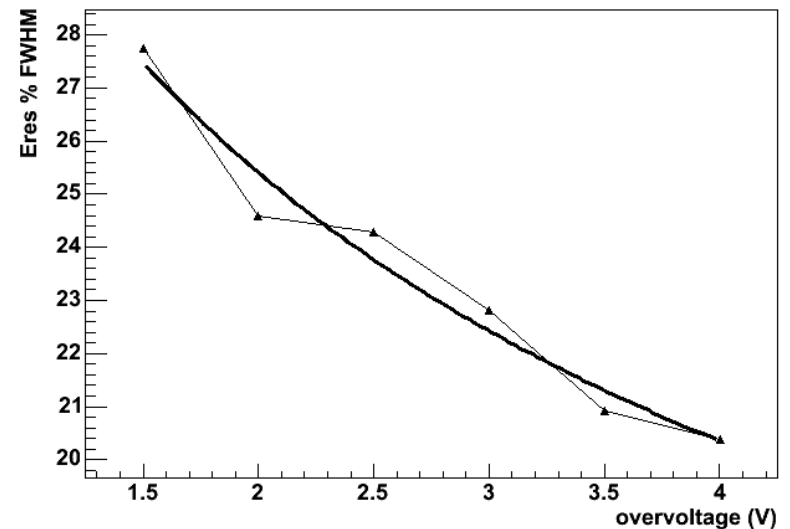
- Peak position $P \sim N_{ph} \times PDE \times G \Rightarrow$ Parabolic with ΔV .
PDE $\propto \Delta V$
 $G = \Delta V \times C_D / qe$
- Energy resolution $R \sim 1/\sqrt{P}$

Peak position vs. overvoltage



Fit parabola: $p_2 \Delta V^2 + p_1 \Delta V + p_0$

Energy resolution vs. overvoltage



Fit : $p_3 / \sqrt{(p_2 \Delta V^2 + p_1 \Delta V + p_0)}$

Results: coincidence timing

- Coincidence measurement with two LSO crystals and two SiPMs

Measured $\sigma t \sim 600$ ps sigma.

- Theory for two scintillators in coincidence:
 $\sigma t = \sqrt{2}\sigma \sim 567$ ps .

Where

$$\sigma \sim \frac{\sqrt{Q} \tau}{\langle N \rangle}$$

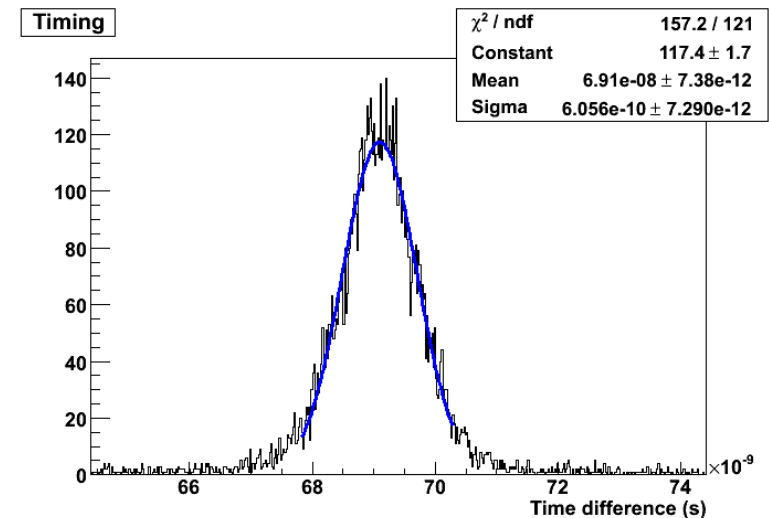
Post, Schiff. Phys. Rev. 80 p. 1113 (1950).

$\langle N \rangle$ = average number of photons: ~ 100 photons at the photopeak.

Q = Trigger level: ~ 1 photoelectron.

τ = Decay time of the scintillator ~ 40 ns

Measurements in agreement with what we expect.



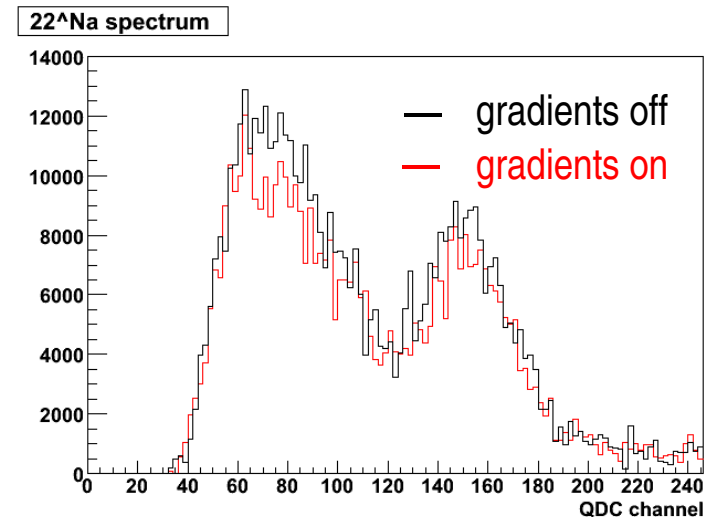
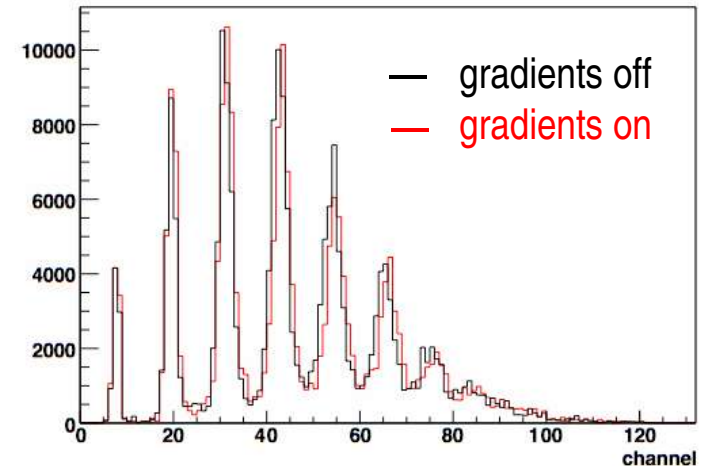
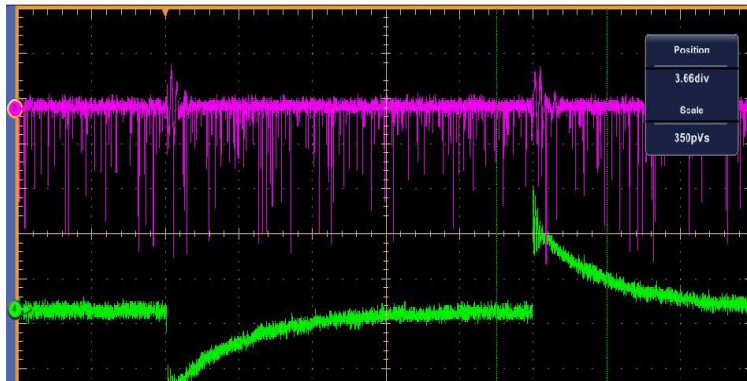
Results: tests in MR system

- S.p.e and ^{22}Na energy spectra acquired with gradients off (black line) and on (red line).

No difference is appreciated in the data.

- Differences in peak position due to temp changes in the magnet (change in gain due to variation in breakdown voltage). No variation for short acquisition time.

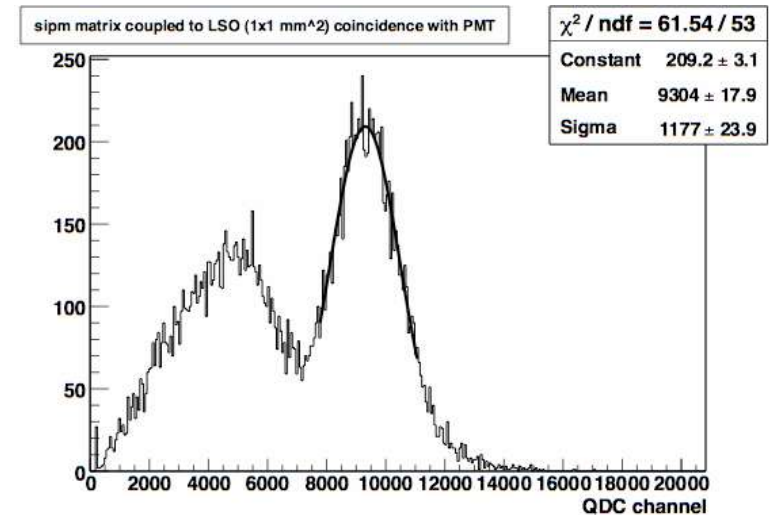
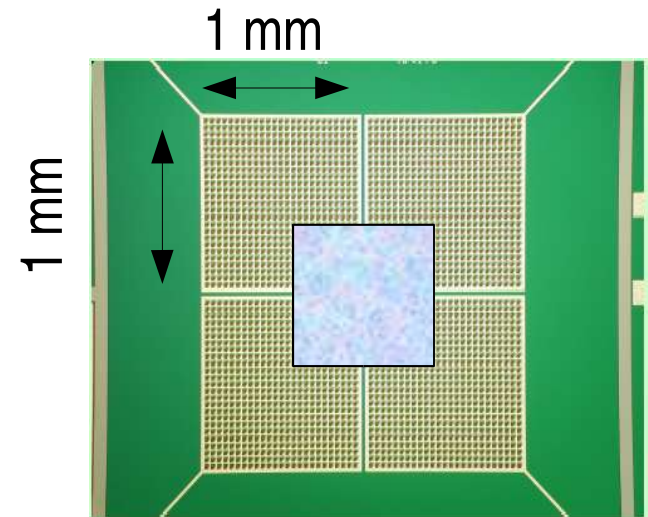
- Pickup in baseline when switching on and off.



Results: matrices

- Test matrices of 4 SiPM pixels in the same substrate tested.
- Home made 4 amplifier board.
- Coincidence with scintillator+PMT.
- Signals from the 4 SiPMs acquired independently and summed up.
- Energy resolution 30% FWHM.
 - Same as taking the data with one of the SiPMs in the matrix.
 - Same as single SiPM with similar GF.

NO degradation wrt single SiPMs.



Application to medical imaging: high resolution PET

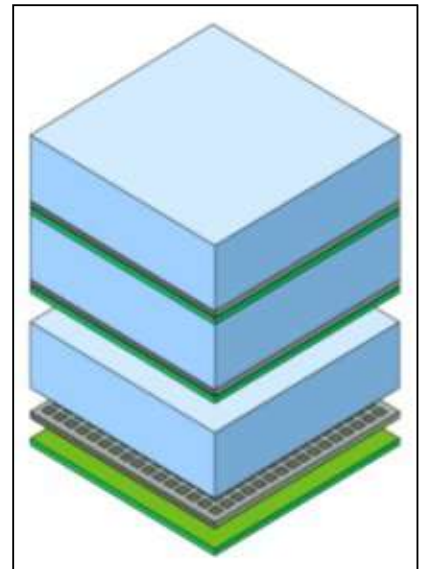
The use of SiPM matrices allows significant improvements in the design of a detector head for a small animal PET tomograph:

- High photodetection efficiency: SiPM matrices leave low dead area wrt arrays of single SiPMs.
- Stack of several detector layers thanks to compactness:
 - Scintillator thickness can be increased => High efficiency
 - DOI information that reduces parallax error => high spatial resolution.

Use of continuous scintillator slabs + finely pixellated SiPM matrix instead of segmented scintillator blocks + PSPMT:

- Very good spatial resolution maintaining high efficiency.
- low cost.

MR compatibility: SiPMs are compact (detectors fit in magnet bore) and insensitive to magnetic fields.



Detector head performance

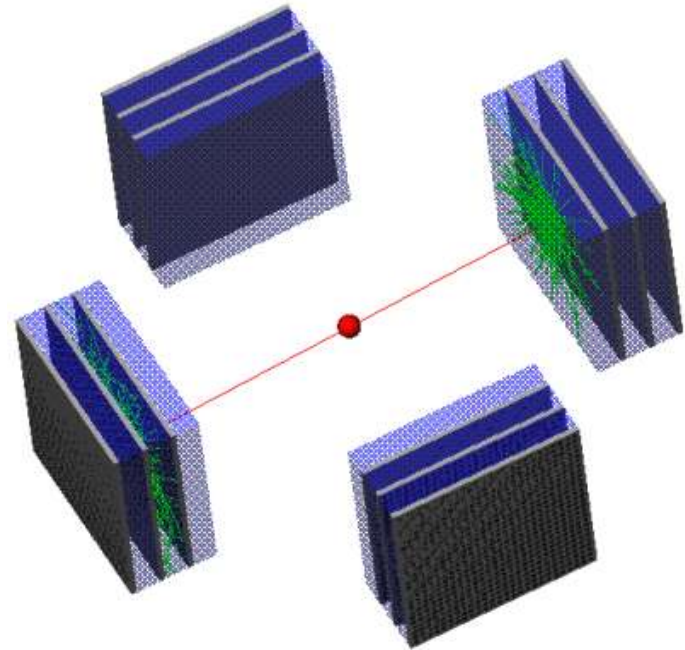
- Geometry optimization and performance estimated with GEANT4 simulations.
- Head geometry: stack of three detector layers (4 cm x 4 cm).
 - Scintillator: continuous slab of LSO or LYSO, 5 mm thick.
 - SiPM matrix with 1.5 mm pitch elements as photodetector.
- Head performance:
 - About **70% efficiency** for 511 keV photons.
 - **Intrinsic spatial resolution – 0.3 mm FWHM** in the center of the crystal < 1mm in the edges.
 - Center-of-gravity position determination algorithms worsen resolution and displacement errors towards the edges.
 - ML methods (skeweness and barycenter based) reduce error towards the edges.
 - backscattering within a detector head < 5%.
- Maximum parallax error for two detector heads at 10 cm: 1 mm.

S. Moehrs et al. *A detector head design for small-animal PET with silicon photomultipliers (SiPM)*. *Phys. Med. Biol.* 51 (2006) 1113-1127.

PET applications: VHR PET

4-head tomograph (same concept as YAP(S)-PET):

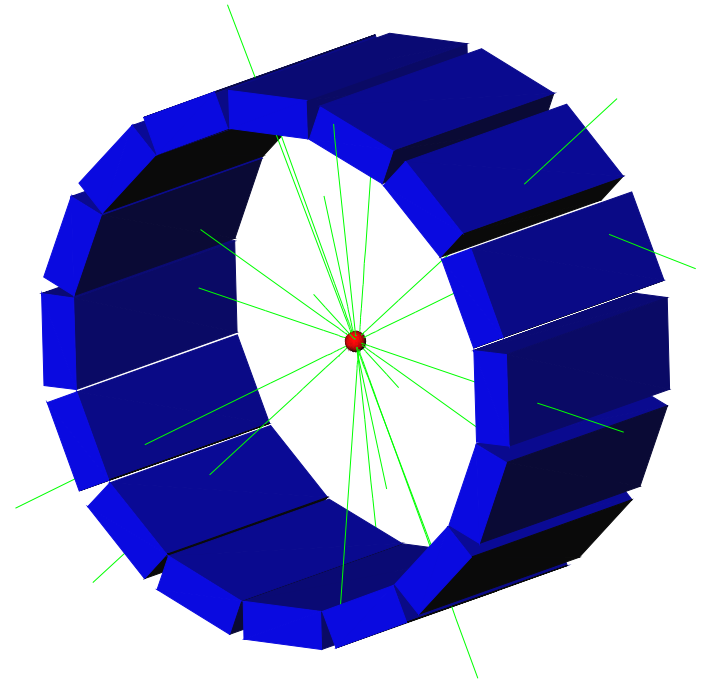
- 2(4) rotating detector heads at 10-15 cm distance.
- FOV 4 cm axial, 4 cm transaxial.
- efficiency around 4%.
- Spatial resolution well below 1 mm³ for a point source in the CFOV.
- low cost.



PET applications: MR compatible ring tomograph

PET insert for simultaneous PET/MR.

- 16 detector heads, 7 cm x 2.4 cm;
- FOV axial 7 cm, transaxial FOV ~6 cm.
- Spatial resolution: 0.76 mm for a ^{18}F point source in the CFOV with FBP.
- efficiency around 11% for 250 keV energy threshold.
- To be inserted in magnet bore.



Conclusions

- SiPMs are a novel type of solid state photodetectors, with important advantages over the existing ones and potential for improvement.
- FBK-irst is developing [SiPMs and SiPM matrices](#). The first results obtained are extremely encouraging. [New devices with improved characteristics](#) have been produced and are being tested.
- SiPMs from FBK-irst have been [evaluated](#) for their use in the PET tomograph construction. The [results obtained are very good](#): energy resolution 20% FWHM for 511 keV photons, intrinsic timing resolution of 60 ps sigma, and 600 ps coincidence timing resolution. The possibility of employing SiPMs in an MR system has been assessed.
- A [very high resolution PET tomograph for small animals](#) and [a MR compatible PET insert](#) employing [SiPMs](#), are under development at the University of Pisa. A [spatial resolution of 0.76 mm FWHM](#) is expected for a ^{18}F point source in water in the centre of the FOV, with FBP, according to GEANT4 simulations.

- Several presentations accepted at IEEE NSS-MIC 2007
 - N41-2: C. Piemonte. *Recent Progress in the Performance of Silicon Photomultipliers produced at FBK-irst.*
 - M14-4: G. Llosa et al. *Silicon Photomultipliers and SiPM matrices as photodetectors for Scintillator readout in Nuclear Medicine.*
 - M18-11: R. Hawkes et al. *Silicon Photomultiplier performance tests in Magnetic Resonance Pulsed Fields.*
 - N15-49: C. Marzocca et al. Preliminary results from a Current-Mode CMOS Front-end circuit for Silicon Photomultiplier detectors.

See you in Hawaii !!